NSN 5962-01-344-9319

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View Online at https://aerobasegroup.com/nsn/5962-01-344-9319

Overall Length:

- 1.285 inches
- **Overall Height:**
- 0.325 inches

Body Length:

- 1.285 inches
- **Body Width:**
- 0.600 inches

Body Height:

0.175 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Electrostatic sensitive and hermetically sealed and burn in and w/enable and programmable and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Hi-performance mos

Input Circuit Pattern:

22 input

Criticality Code Justification:

Feat

Current Rating Per Characteristic:

140.00 milliamperes reverse current, dc absolute

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 6.0 volts power source

Capitance Rating Per Characteristic:

Err-060 and err-060

Time Rating Per Chacteristic:

350.00 nanoseconds delay

Memory Device Type:

Eeprom

Special Features:

Nuclear hardness critical item

Unpackaged Unit Weight:

6.5 grams

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AeroBase Group

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0